1A1 THRU 1A7

SILICON RECTIFIERS Voltage Range – 50 to 1000 Volts Current – 1.0 Amperes

Features

- High reliability
- Low leakage
- Low forward voltage drop
- High current capability

Mechanical Data

- Case: Molded plastic black body
- Lead: MIL-STD 202E method 208C guaranteed.
- Mounting Position: Any

Absolute Maximum Ratings and Characteristics

Ratings at 25°Cambient temperature unless otherwise specified.. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

		Symbols	1A1	1A2	1A3	1A4	1A5	1A6	1A7	Units
Maximum repetitive peak reverse voltage		V _{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage		V _{RMS}	35	70	140	280	420	560	700	V
Maximum DC blocking voltage		V _{DC}	50	100	200	400	600	800	1000	V
Maximum average forward rectified current at $T_A = 25$ ^{O}C		Ι _ο	1.0							A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)		I _{FSM}	25							A
Maximum instantaneous forward voltage at 1A DC		V _F	1.1							V
Maximum DC reverse current at rated DC blocking voltage	@T _A = 25 ^O C		5.0							uA
	$@T_A = 100^{\circ}C$	I _R	50							
Maximum full load reverse current full cycle average 0.375" (9.5mm) lead length at T _L =75°C			100							uA
Typical junction capacitance (note)		CJ	15							pF
Typical thermal resistance		$R_{ ext{ heta}JA}$	60							^o C/W
Operating and storage temperature range		T _J ,T _S	-65 to +150							°C

Note: Measured at 1MHz and applied reverse voltage of 4V.









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Dimensions in mm

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RATING AND CHARACTERISTIC CURVES (1A1 thru 1A7)





VOLTAGE(V)



FIG.5-TYPICAL JUNCTION CAPACITANCE













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